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## **RFMD(R) Supplies EDGE Power Amplifier to Samsung for Stylish E250 EDGE Slider Phone**

RFMD's Leadership in Linear and Large Signal Polar Modulation EDGE Power Amplifiers is Supporting Samsung's Projected Growth in the EDGE Market

GREENSBORO, N.C.--(BUSINESS WIRE)--May 16, 2007--RF Micro Devices, Inc. (NASDAQ: RFMD), a global leader in the design and manufacture of high-performance radio systems and solutions for applications that drive mobile communications, today announced that its RF3159 quad-band linear EDGE power amplifier (PA) module is supporting Samsung's E250 EDGE handset.

The Samsung E250 provides consumers state-of-the-art performance and advanced multimedia functionality in a sleek, compact design. The highly stylish E250 slider phone features a VGA camera, an MP3 player, advanced audio distribution profile (A2DP) stereo Bluetooth® capability and a vivid 2.0" color screen. The Samsung E250 is currently among Samsung's best selling handsets.

"We are very pleased that Samsung has selected the RF3159 to power the highly popular and stylish E250 handset," said Konrad Alvarino, general manager, components business unit at RFMD. "Top tier handset manufacturers such as Samsung continue to select our linear EDGE power amplifiers as a result of their superior efficiency and linearity performance. We look forward to supporting Samsung with our industry-leading EDGE power amplifiers in future EDGE and 3G multimode handsets."

The RF3159 is a high linearity quad-band GSM/GPRS/EDGE PA designed to support EDGE transceivers utilizing a linear transmit architecture, including transceivers by NXP Semiconductors and Infineon Technologies. Designed to be the final amplification stage in a dual-mode GSM/GPRS/EDGE mobile transmit lineup, the product's gain and linearity lineups enable handset manufacturers to optimize the transmit chain to meet varying implementations of linearity, efficiency and output power. Fully quad-band capable, the RF3159 operates in the 824MHz to 915MHz and 1710MHz to 1910MHz bands.

RFMD is the leading supplier of linear EDGE and large signal polar modulation (LSPM) EDGE power amplifiers. The Company anticipates additional tier-one EDGE handsets will feature its linear EDGE PA modules this year. Additionally, the Company recently sampled two new EDGE front end products - the RF3161 LSPM EDGE PA module and the RF3203 linear EDGE transmit module (TxM) - and RFMD anticipates continued favorable design activity related to its industry-leading EDGE product portfolio.

About RFMD: RF Micro Devices, Inc. (NASDAQ: RFMD) is a global leader in the design and manufacture of high-performance radio systems and solutions for applications that drive mobile communications. RFMD's power amplifiers, transmit modules, cellular transceivers and system-on-chip (SOC) solutions enable worldwide mobility, provide enhanced connectivity and support advanced functionality in current- and next-generation mobile handsets, cellular base stations, wireless local area networks (WLANs), wireless personal area networks (WPANs) and global positioning systems (GPS). Recognized for its diverse portfolio of state-of-the-art semiconductor technologies and vast RF systems expertise, RFMD is a preferred supplier enabling the world's leading mobile device manufacturers to deliver advanced wireless capabilities that satisfy current and future market demands.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001- certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at [www.rfmd.com](http://www.rfmd.com).

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including variability in quarterly operating results, the rate of growth and development of wireless markets, risks associated with the operation of our wafer fabrication facilities, molecular beam epitaxy facility, assembly facility and test and

tape and reel facilities, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, our ability to reduce costs and improve gross margins by implementing innovative technologies, our ability to bring new products to market, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on a limited number of customers, and dependence on third parties. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward- looking statements.

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CONTACT: RF Micro Devices, Inc.  
Douglas DeLieto, 336-678-5091  
Vice President, IR  
or  
Brian K. Cockman, 336-678-8945  
Public Relations

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